



IXGT32N60BD1 Information

Part Number IXGT32N60BD1

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT 600V 60A 200W TO268

Package TO-268-3, D3Pak (2 Leads + Tab), TO-268AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXGT32N60BD1 Specifications

Manufacturer Part Number	IXGT32N60BD1
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-268-3, D3Pak (2 Leads + Tab), TO-268AA
Series	HiPerFAST?
IGBT Type	-
Voltage - Collector Emitter Breakdown (Max)	600V
Current - Collector (Ic) (Max)	60A
Current - Collector Pulsed (Icm)	120A
Vce(on) (Max) @ Vge, Ic	2.3V @ 15V, 32A
Power - Max	200W
Switching Energy	600μJ (off)
Input Type	Standard
Gate Charge	110nC
Td (on/off) @ 25°C	25ns/100ns
Test Condition	480V, 32A, 4.7 Ohm, 15V
Reverse Recovery Time (trr)	25ns
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-268-3, D3Pak (2 Leads + Tab), TO-268AA
Supplier Device Package	TO-268
	Report errors?

IXGT32N60BD1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXGT32N60BD1 Payment Methods



















IXGT32N60BD1 Shipping Methods













If you have any question about IXGT32N60BD1, please do not hesitate to contact us!

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